

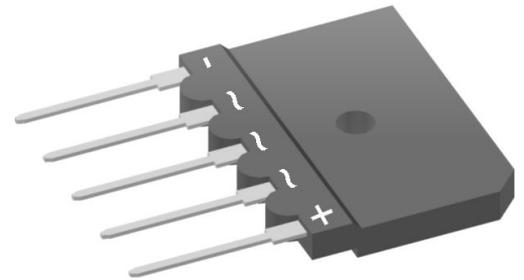
Standard Rectifier

3~ Rectifier	
$V_{RRM} =$	800 V
$I_{DAV} =$	40 A
$I_{FSM} =$	370 A

3~ Rectifier Bridge

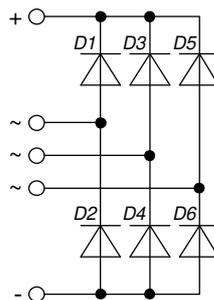
Part number

GUO40-08NO1



Backside: isolated

 E72873



Features / Advantages:

- Low forward voltage drop
- Planar passivated chips
- Easy to mount with one screw
- Space and weight savings

Applications:

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: GUPP

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

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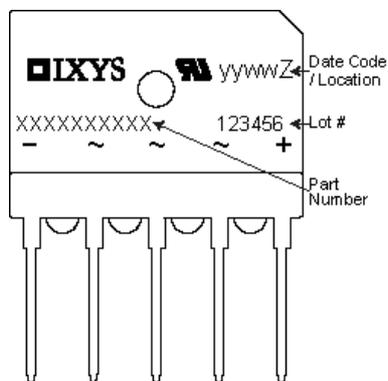
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Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage					900	V
V_{RRM}	max. repetitive reverse blocking voltage					800	V
I_R	reverse current	$V_R = 800\text{ V}$		$T_{VJ} = 25^\circ\text{C}$		40	μA
		$V_R = 800\text{ V}$		$T_{VJ} = 150^\circ\text{C}$		1.5	mA
V_F	forward voltage drop	$I_F = 10\text{ A}$		$T_{VJ} = 25^\circ\text{C}$		1.06	V
		$I_F = 30\text{ A}$				1.28	V
		$I_F = 10\text{ A}$		$T_{VJ} = 150^\circ\text{C}$		0.92	V
		$I_F = 30\text{ A}$				1.23	V
I_{DAV}	bridge output current	$T_C = 90^\circ\text{C}$		$T_{VJ} = 175^\circ\text{C}$		40	A
		rectangular	$d = \frac{1}{3}$				
V_{FO}	threshold voltage			$T_{VJ} = 175^\circ\text{C}$		0.74	V
r_F	slope resistance					16.3	m Ω
						} for power loss calculation only	
R_{thJC}	thermal resistance junction to case					4.3	K/W
R_{thCH}	thermal resistance case to heatsink				0.5		K/W
P_{tot}	total power dissipation			$T_C = 25^\circ\text{C}$		35	W
I_{FSM}	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$		$T_{VJ} = 45^\circ\text{C}$		370	A
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$		$V_R = 0\text{ V}$		400	A
		$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$		$T_{VJ} = 150^\circ\text{C}$		315	A
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$		$V_R = 0\text{ V}$		340	A
I^2t	value for fusing	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$		$T_{VJ} = 45^\circ\text{C}$		685	A ² s
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$		$V_R = 0\text{ V}$		665	A ² s
		$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$		$T_{VJ} = 150^\circ\text{C}$		495	A ² s
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$		$V_R = 0\text{ V}$		480	A ² s
C_J	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$		10	pF



Package GUPF		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			70	A
T_{VJ}	virtual junction temperature		-40		175	°C
T_{op}	operation temperature		-40		150	°C
T_{stg}	storage temperature		-40		150	°C
Weight				8.5		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	6.7	5.4		mm
$d_{Spb/Apb}$		terminal to backside	10.0	8.0		mm
V_{ISOL}	isolation voltage	t = 1 second		2500		V
		t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	2100		V
R_{thJA}	thermal resistance junction to ambient			50		K/W



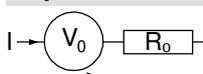
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	GUO40-08NO1	GUO40-08NO1	Tube	14	514885

Similar Part	Package	Voltage class
DNA40U2200GU	GUPF	2200
DMA40U1800GU	GUPF	1800
GUO40-16NO1	GUPF	1600
GUO40-12NO1	GUPF	1200

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 175^{\circ}\text{C}$



$V_{0\ max}$	threshold voltage	0.74	V
$R_{0\ max}$	slope resistance *	13.7	mΩ



Rectifier

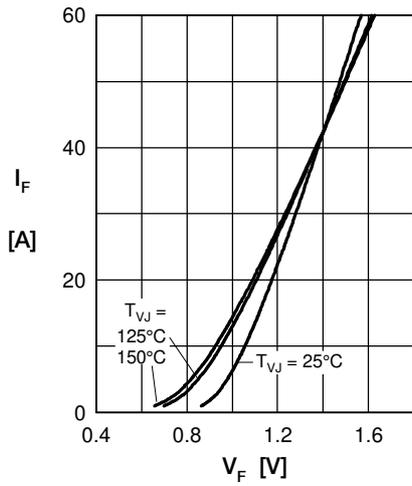


Fig. 1 Forward current vs. voltage drop per diode

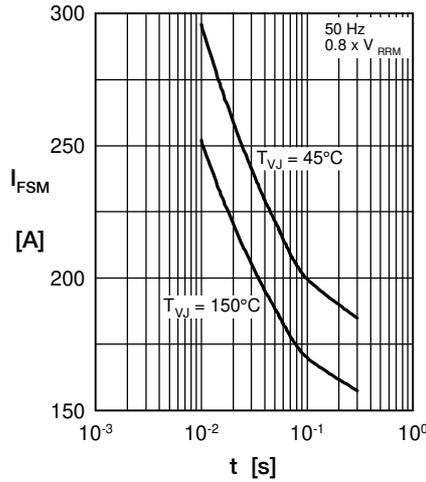


Fig. 2 Surge overload current vs. time per diode

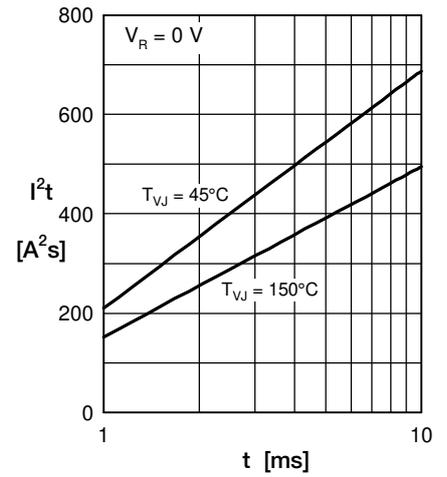


Fig. 3 I^2t vs. time per diode

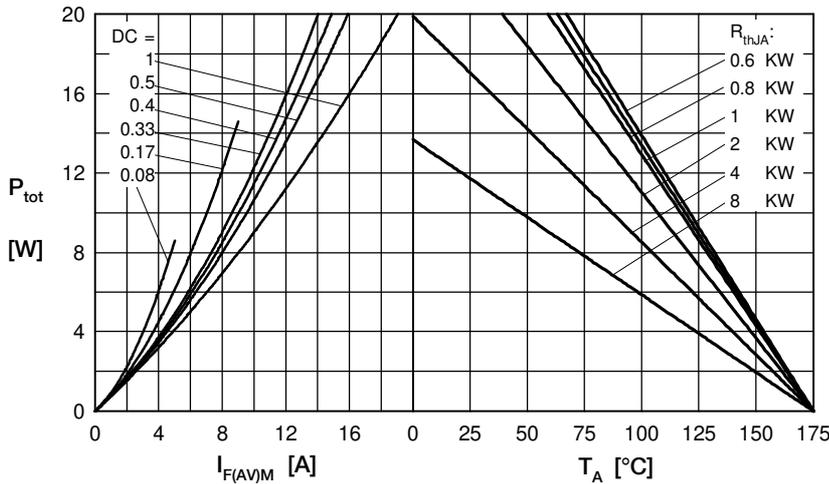


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

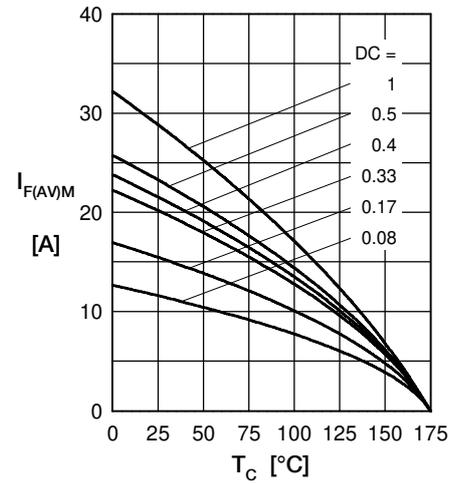


Fig. 5 Max. forward current vs. case temperature per diode

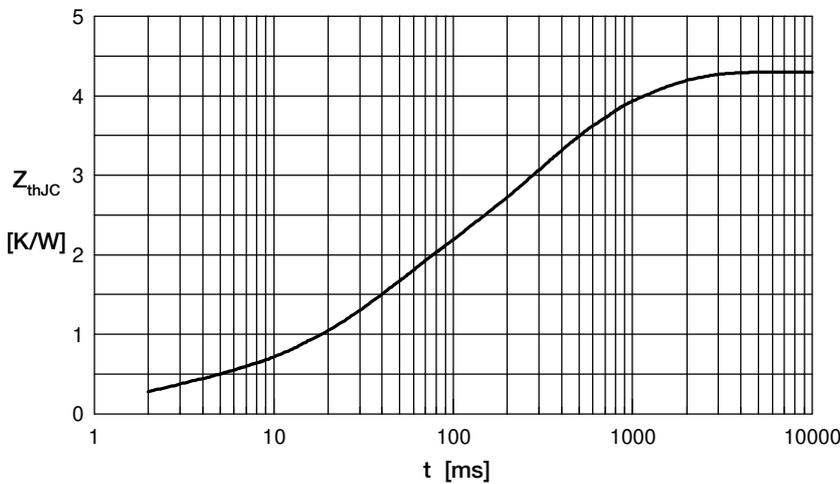


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.302	0.002
2	1.252	0.032
3	1.582	0.227
4	1.164	0.820

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